

Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Block Oriented 24-Bit Sequencer
- Configurable as Two Independent 12-Bit Sequencers
- 24 x 24 Crosspoint Switch
- Programmable Delay on 12 Outputs 9-
- Multi-Chip Synchronization Signals
- Standard μ P Interface
- 100pF Drive on Outputs
- DC to 40MHz Clock Rate

Applications

- 1-D, 2-D Filtering
- Pan/Zoom Addressing
- FFT Processing
- Matrix Math Operations

Ordering Information

| PART NUMBER | TEMP. RANGE (°C) | PACKAGE | PKG. NO. |
|-------------------|------------------|-----------|----------|
| HSP45240GM-25/883 | -55 to 125 | 68 Ld PGA | |
| HSP45240GM-33/883 | -55 to 125 | 68 Ld PGA | |
| HSP45240GM-40/883 | -55 to 125 | 68 Ld PGA | |

Description

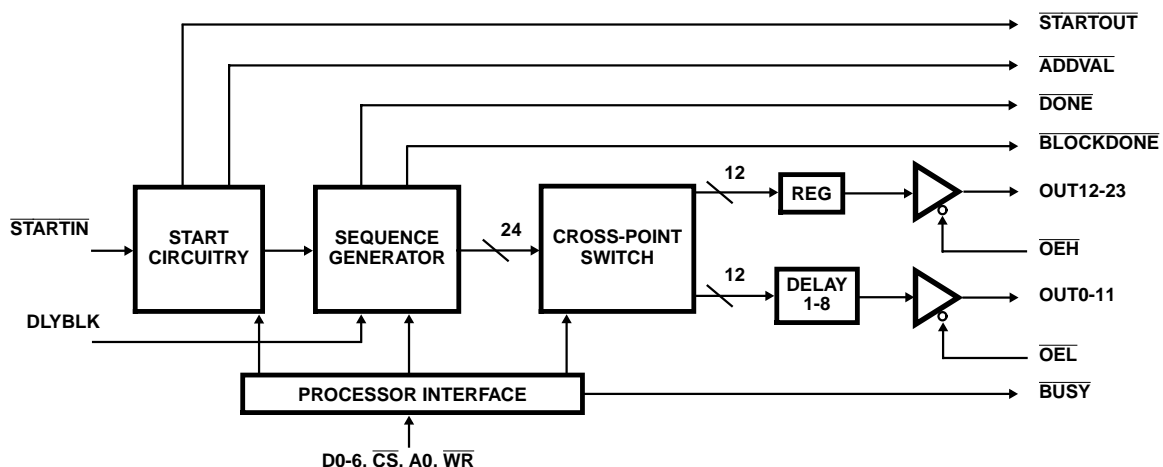
The Intersil HSP45240/883 is a high speed Address Sequencer which provides specialized addressing for functions like FFTs, 1-D and 2-D filtering, matrix operations, and image manipulation. The sequencer supports block oriented addressing of large data sets up to 24 bits at clock speeds up to 40MHz.

Specialized addressing requirements are met by using the onboard 24 x 24 crosspoint switch. This feature allows the mapping of the 24 address bits at the output of the address generator to the 24 address outputs of the chip. As a result, bit reverse addressing, such as that used in FFTs, is made possible.

A single chip solution to read/write addressing is also made possible by configuring the HSP45240 as two 12-bit sequencers. To compensate for system pipeline delay, a programmable delay is provided on 12 of the address outputs.

The HSP45240 is manufactured using an advanced CMOS process, and is a low power fully static design. The configuration of the device is controlled through a standard microprocessor interface and all inputs/outputs, with the exception of clock, are TTL compatible.

Block Diagram



HSP45240/883

Absolute Maximum Ratings

Supply Voltage +8.0V
 Input, Output Voltage Applied GND -0.5V to V_{CC} +0.5V
 ESD Classification Class 1

Operating Conditions

Temperature Range -55°C to 125°C
 Voltage Range +4.5V to +5.5V

Thermal Information

Thermal Resistance (Typical, Note 1) θ_{JA} (°C/W) θ_{JC} (°C/W)
 PGA Package 37.1 10.1
 Maximum Package Power Dissipation at 125°C
 PGA Package 1.35W
 Maximum Junction Temperature 175°C
 Maximum Storage Temperature Range -65°C to 150°C
 Maximum Lead Temperature (Soldering 10s) 300°C

Die Characteristics

Gate Count 8,388

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

- θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

TABLE 1. DC ELECTRICAL SPECIFICATIONS

Device Guaranteed and 100% Tested

| PARAMETER | SYMBOL | TEST CONDITIONS | GROUP A SUB- GROUPS | TEMPERATURE (°C) | LIMITS | | UNITS |
|--------------------------------|------------|---|---------------------------|-------------------------|--------|-----|---------|
| | | | | | MIN | MAX | |
| Logical One Input Voltage | V_{IH} | $V_{DD} = 5.5V$ | 1, 2, 3 | $-55 \leq T_A \leq 125$ | 2.2 | - | V |
| Logical Zero Input Voltage | V_{IL} | $V_{DD} = 4.5V$ | 1, 2, 3 | $-55 \leq T_A \leq 125$ | - | 0.8 | V |
| Output HIGH Voltage | V_{OH} | $I_{OH} = -400\mu A$ $V_{DD} = 4.5V$ (Note 2) | 1, 2, 3 | $-55 \leq T_A \leq 125$ | 2.6 | - | V |
| Output LOW Voltage | V_{OL} | $I_{OL} = +2.0mA$ $V_{CC} = 4.5V$ (Note 2) | 1, 2, 3 | $-55 \leq T_A \leq 125$ | - | 0.4 | V |
| Input Leakage Current | I_I | $V_{IN} = V_{CC}$ or GND $V_{CC} = 5.5V$ | 1, 2, 3 | $-55 \leq T_A \leq 125$ | -10 | +10 | μA |
| Output Leakage Current | I_O | $V_{OUT} = V_{CC}$ or GND $V_{CC} = 5.5V$ | 1, 2, 3 | $-55 \leq T_A \leq 125$ | -10 | +10 | μA |
| Clock Input High | V_{IHC} | $V_{CC} = 5.5V$ | 1, 2, 3 | $-55 \leq T_A \leq 125$ | 3.0 | - | V |
| Clock Input Low | V_{ILC} | $V_{CC} = 4.5V$ | 1, 2, 3 | $-55 \leq T_A \leq 125$ | - | 0.8 | V |
| Standby Power Supply Current | I_{CCSB} | $V_{IN} = V_{CC}$ or GND $V_{CC} = 5.5V$, Outputs Open | 1, 2, 3 | $-55 \leq T_A \leq 125$ | - | 500 | μA |
| Operating Power Supply Current | I_{CCOP} | $f = 33MHz$ $V_{CC} = 5.5V$ (Note 3) | 1, 2, 3 | $-55 \leq T_A \leq 125$ | - | 99 | mA |
| Functional Test | FT | (Note 4) | 7, 8 | $-55 \leq T_A \leq 125$ | - | - | |

NOTES:

- Interchanging of force and sense conditions is permitted.
- Operating Supply Current is proportional to frequency, typical rating is 3mA/MHz.
- Tested as follows: $t = 1MHz$, $V_{IH} = 2.6$, $V_{IL} = 0.4$, $V_{OH} \geq 1.5V$, $V_{OL} \leq 1.5V$, $V_{IHC} = 3.4V$, and $V_{ILC} = 0.4V$.

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TABLE 2. AC ELECTRICAL SPECIFICATIONS

Device Guaranteed and 100% Tested

| PARAMETER | SYMBOL | GROUP A SUBGROUP | TEMPERATURE (°C) | -25 (25MHz) | | -33 (33MHz) | | -40 (40MHz) | | UNITS |
|--|------------------|------------------|----------------------------|----------------|-----|-------------|-----|-------------|-----|-------|
| | | | | MIN | MAX | MIN | MAX | MIN | MAX | |
| Clock Period | t _{CP} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 39 | - | 30 | - | 25 | - | ns |
| Clock Pulse Width High | t _{CH} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 15 | - | 12 | - | 10 | - | ns |
| Clock Pulse Width Low | t _{CL} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 15 | - | 12 | - | 10 | - | ns |
| Setup Time D0-6 to \overline{WR} High | t _{DS} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 17 | - | 16 | - | 14 | - | ns |
| Hold Time D0-6 from \overline{WR} Low | t _{DH} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 0 | - | 0 | - | 0 | - | ns |
| Setup Time A, \overline{CS} to \overline{WR} Low | t _{AS} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 5 | - | 5 | - | 5 | - | ns |
| Hold Time A, \overline{CS} from \overline{WR} High | t _{AH} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 0 | - | 0 | - | 0 | - | ns |
| Pulse Width for \overline{WR} Low | t _{WRL} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 18 | - | 14 | - | 12 | - | ns |
| Pulse Width for \overline{WR} High | t _{WRH} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 18 | - | 14 | - | 12 | - | ns |
| \overline{WR} Cycle Time | t _{WP} | 9,10,11 | -55 ≤ T _A ≤ 125 | 39 | - | 30 | - | 25 | - | ns |
| Set-up Time $\overline{STARTIN}$, \overline{DLYBLK} , to Clock High | t _{IS} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 15 | - | 12 | - | 10 | - | ns |
| Hold Time $\overline{STARTIN}$, \overline{DLYBLK} , to Clock High | t _{IH} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 0 | - | 0 | - | 0 | - | ns |
| Clock to Output Prop. Delay on OUT0-23 | t _{PDO} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | - | 18 | - | 16 | - | 14 | ns |
| Clock to Prop. Delay, on $\overline{STARTOUT}$, $\overline{BLKDONE}$, \overline{DONE} , \overline{ADVAL} , and \overline{BUSY} | t _{PDS} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | - | 18 | - | 16 | - | 14 | ns |
| Output Enable Time (Note 6) | t _{EN} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | - | 22 | - | 20 | - | 15 | ns |
| \overline{RST} Low Time | t _{RST} | 9, 10, 11 | -55 ≤ T _A ≤ 125 | 2 Clock Cycles | | | | | | ns |

NOTES:

5. AC Testing: V_{CC} = 4.5V and 5.5V, inputs are driven at 3.0V for Logic "1" and 0.0V for a Logic "0". Input and output timing measurements are made at 1.5V for both a logic "1" and "0". CLK is driven at 4.0V and 0V and measured at 2.0V.
6. Transition is measured at ±200mV from steady state voltage with loading as specified by test load circuit and C_L = 40pF.

TABLE 3. ELECTRICAL PERFORMANCE SPECIFICATIONS

| PARAMETERS | SYMBOL | TEST CONDITIONS | NOTES | TEMPERATURE | -25 (25MHz) | | -33 (33MHz) | | -40 (40MHz) | | UNITS |
|--------------------|------------------|--|-------|----------------------------|-------------|-----|-------------|-----|-------------|-----|-------|
| | | | | | MIN | MAX | MIN | MAX | MIN | MAX | |
| Input Capacitance | C _{IN} | V _{CC} = Open, f = 1MHz, All measurements are referenced to device GND. | 7 | T _A = 25 | - | 10 | - | 10 | - | 10 | pF |
| Output Capacitance | C _{OUT} | V _{CC} = Open, f = 1MHz, All measurements are referenced to device GND. | 7 | T _A = 25 | - | 10 | - | 10 | - | 10 | pF |
| Output Disable | t _{OEZ} | | 7, 8 | -55 ≤ T _A ≤ 125 | - | 22 | - | 20 | - | 15 | ns |

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TABLE 3. ELECTRICAL PERFORMANCE SPECIFICATIONS (Continued)

| PARAMETERS | SYMBOL | TEST CONDITIONS | NOTES | TEMPERATURE | -25 (25MHz) | | -33 (33MHz) | | -40 (40MHz) | | UNITS |
|------------------|----------|-----------------|-------|-------------------------|------------------|----------|----------------|------|-------------------------|-----|-------|
| | | | | | MIN | MAX | MIN | MAX | MIN | MAX | |
| | | | | | Output Rise Time | t_{OR} | | 7, 8 | $-55 \leq T_A \leq 125$ | - | |
| Output Fall Time | t_{OF} | | 7, 8 | $-55 \leq T_A \leq 125$ | - | 5 | - | 5 | - | 3 | ns |

NOTES:

7. Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested. These parameters are characterized upon initial design and after major process and/or design changes.

8. Loading is as specified in the test load circuit with $C_L = 40pF$.

TABLE 4. ELECTRICAL TEST REQUIREMENTS

| CONFORMANCE GROUPS | METHOD | SUBGROUPS |
|--------------------|--------------|-------------------------------|
| Initial Test | 100%/5004 | - |
| Interim Test | 100%/5004 | - |
| PDA | 100% | 1 |
| Final Test | 100% | 2, 3, 8A, 8B, 10, 11 |
| Group A | - | 1, 2, 3, 7, 8A, 8B, 9, 10, 11 |
| Groups C and D | Samples/5005 | 1, 7, 9 |

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Burn-In Circuit

| | | | | | | | | | | | |
|---|-------------------|-------------------|-------------------|-----------------|-----------------|---------------|-----------------|-------|-----------------|-------|-----------------|
| L | | OE \overline{H} | DLY BLK | START OUT | V _{CC} | BLOCK DONE | GND | OUT1 | OUT2 | NC | |
| K | NC | NC | OE \overline{L} | START IN | ADD VAL | BUSY | DONE | OUT0 | V _{CC} | NC | OUT3 |
| J | RST $\overline{}$ | V _{CC} | | | | | | | | GND | OUT4 |
| H | CLK | GND | | | | | | | | OUT5 | V _{CC} |
| G | CS $\overline{}$ | A0 | | | | | | | | OUT6 | OUT7 |
| F | WR $\overline{}$ | GND | | | | | | | | GND | OUT8 |
| E | D6 | D5 | | | | | | | | OUT9 | V _{CC} |
| D | D4 | D3 | | | | | | | | OUT10 | OUT11 |
| C | D2 | D1 | | | | | | | | GND | OUT12 |
| B | D0 | NC | OUT22 | OUT21 | GND | OUT18 | OUT17 | GND | OUT14 | NC | NC |
| A | | GND | OUT23 | V _{CC} | OUT20 | OUT19 | V _{CC} | OUT16 | OUT15 | OUT13 | |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 |

| PGA PIN | PIN NAME | BURN- IN SIGNAL | PGA PIN | PIN NAME | BURN- IN SIGNAL | PGA PIN | PIN NAME | BURN- IN SIGNAL | PGA PIN | PIN NAME | BURN- IN SIGNAL |
|------------|-----------------|-----------------------|------------|-----------------|-----------------------|------------|-----------------|-----------------------|------------|---------------------|-----------------------|
| A2 | GND | GND | B9 | OUT14 | V _{CC} /2 | F11 | OUT8 | V _{CC} /2 | K6 | BUSYB | V _{CC} /2 |
| A3 | OUT23 | V _{CC} /2 | C1 | D2 | F10 | G1 | CSB | F5 | K7 | DONEB | V _{CC} /2 |
| A4 | V _{CC} | V _{CC} | C2 | D1 | F9 | G2 | A0 | F6 | K8 | OUT0 | V _{CC} /2 |
| A5 | OUT20 | V _{CC} /2 | C10 | GND | GND | G10 | OUT6 | V _{CC} /2 | K9 | V _{CC} | V _{CC} |
| A6 | OUT19 | V _{CC} /2 | C11 | OUT12 | V _{CC} /2 | G11 | OUT7 | V _{CC} /2 | K11 | OUT3 | V _{CC} /2 |
| A7 | V _{CC} | V _{CC} | D1 | D4 | F12 | H1 | CLK | F0 | L2 | OE \overline{H} B | F13 |
| A8 | OUT16 | V _{CC} /2 | D2 | D3 | F11 | H2 | GND | GND | L3 | DLYBLK | F11 |
| A9 | OUT15 | V _{CC} /2 | D10 | OUT10 | V _{CC} /2 | H10 | OUTS | V _{CC} /2 | L4 | STARTOUTB | V _{CC} /2 |
| A10 | OUT13 | V _{CC} /2 | D11 | OUT11 | V _{CC} /2 | H11 | V _{CC} | V _{CC} | LS | V _{CC} | V _{CC} |
| B1 | D0 | F8 | E1 | D6 | F7 | J1 | RSTB | F14 | L6 | BLOCKDONEB | V _{CC} /2 |
| B3 | OUT22 | V _{CC} /2 | E2 | D5 | F13 | J2 | V _{CC} | V _{CC} | L7 | GND | GND |
| B4 | OUT21 | V _{CC} /2 | E10 | OUT9 | V _{CC} /2 | J10 | GND | GND | L8 | OUT1 | V _{CC} /2 |
| B5 | GND | GND | E11 | V _{CC} | V _{CC} | J1 1 | OUT4 | V _{CC} /2 | L9 | OUT2 | V _{CC} /2 |
| B6 | OUT18 | V _{CC} /2 | F1 | WRB | F4 | K3 | OELB | F12 | | | |
| B7 | OUT17 | V _{CC} /2 | F2 | GND | GND | K4 | START1NB | F6 | | | |
| B8 | GND | GND | F10 | GND | GND | K5 | ADVALB | V _{CC} /2 | | | |

NOTES:

9. V_{CC}/2 (2.7V ±10%) used for outputs only.
10. 47Ω (±20%) resistor connected to all pins except V_{CC} and GND.
11. V_{CC} = 5.5 ±0.5V.
12. 0.1μF (min) capacitor between V_{CC} and GND per position.
13. F0 = 100kHz ±10%, F1 = F0/2, F2 = F1/2....., F11 = F10/2, 40% -60% Duty Cycle.
14. Input voltage limits: V_{IL} = 0.8V max., V_{IH} = 4.5V ±10%.

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Die Characteristics

DIE DIMENSIONS:

186 mils x 222 mils x 19 ±1mils

METALLIZATION:

Type: Si - Al or Si-Al-Cu

Thickness: 8kÅ

GLASSIVATION:

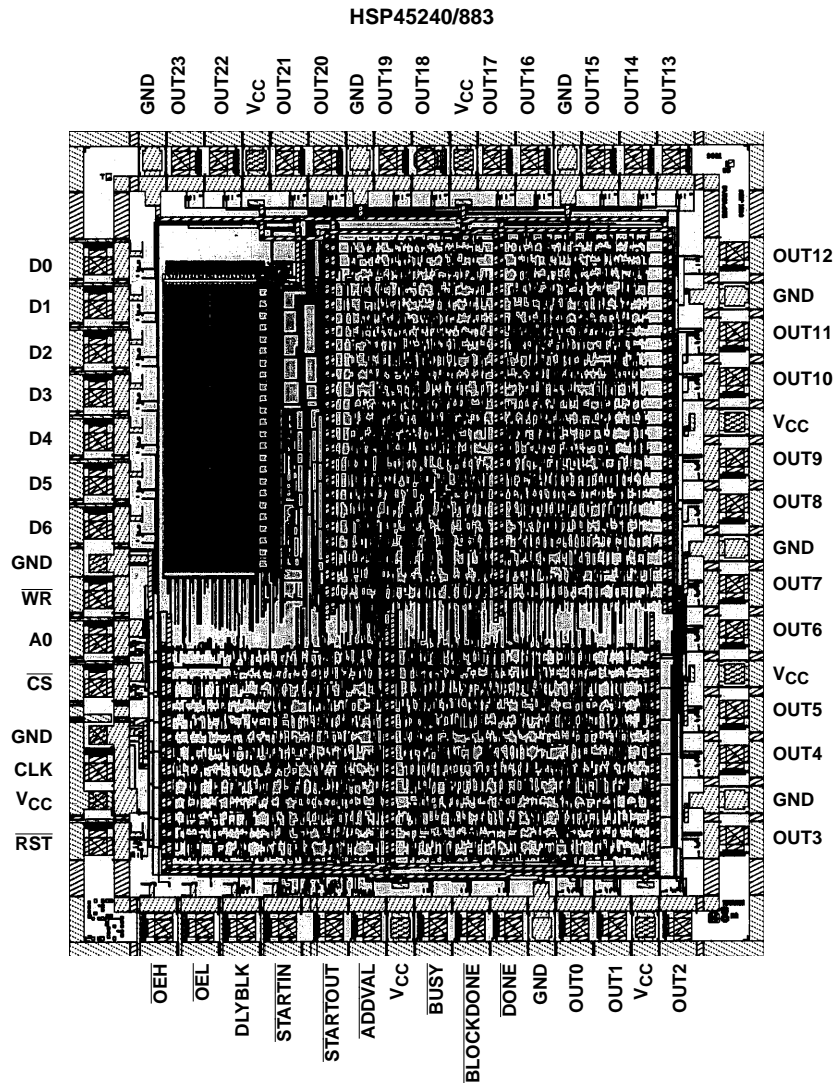
Type: Nitrox

Thickness: 10kÅ

WORST CASE CURRENT DENSITY:

$1.8 \times 10^5 \text{A/cm}^2$

Metallization Mask Layout



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